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# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.50$  V at  $I_F = 5$  A

TMBS<sup>®</sup> TO-220AB ITO-220AB V30120C VF30120C PIN 1 O PIN 2 PIN 1 0 PIN 2 CASE PIN 3 O-PIN 3 O--D<sup>2</sup>PAK (TO-263AB) **TO-262AA** ĸ 3 2 VB30120C VI30120C PIN 1 0 PIN 1 0 PIN 2 -C PIN 2 O HEATSINK PIN 3 Oκ **DESIGN SUPPORT TOOLS** click logo to get started



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PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> 2 x 15 A						
V <sub>RRM</sub> 120 V						
I <sub>FSM</sub>	150 A					
$V_F$ at $I_F = 15$ A	0.68 V					
T <sub>J</sub> max.	150 °C					
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package) RoHS
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

# **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

# **MECHANICAL DATA**

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

#### Polarity: as marked

Mounting Torque: 10 in-lbs max.

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER		SYMBOL	V30120C	VF30120C	VB30120C	VI30120C	UNIT	
Max. repetitive peak reverse voltage			120					
Max. average forward rectified current	per device	I		;	30		А	
(fig. 1)	per diode	I <sub>F(AV)</sub>	15					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150			А		
Non-repetitive avalanche energy at $T_J = 25$ °C, L = 60 mH per diode			130			mJ		
Peak repetitive reverse current at $t_p$ = 2 µs, 1 kHz, $T_J$ = 38 °C $\pm$ 2 °C per diode			0.5			А		
Voltage rate of change (rated V <sub>R</sub> )			10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500				V	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150				°C	

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage	I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	120 (min.)	-	V	
Instantaneous forward voltage per diode $^{(1)}$	$I_F = 5 A$	T <sub>A</sub> = 25 °C	V <sub>F</sub>	0.56	-	V	
	I <sub>F</sub> = 7.5 A			0.71	-		
	I <sub>F</sub> = 15 A			0.86	0.97		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.50	-		
	I <sub>F</sub> = 7.5 A			0.60	-		
	I <sub>F</sub> = 15 A			0.68	0.76		
Reverse current per diode <sup>(2)</sup>	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub>	11	-	μA	
		T <sub>A</sub> = 125 °C		8	-	mA	
	V <sub>B</sub> = 120 V	T <sub>A</sub> = 25 °C		-	800	μA	
	v <sub>R</sub> = 120 v	T <sub>A</sub> = 125 °C		17	50	mA	

Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	V30120C	VF30120C	VB30120C	VI30120C	UNIT	
Typical thermal resistance per diode	$R_{\theta JC}$	2.2	4.5	2.2	2.2	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V30120C-E3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VF30120C-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB30120C-E3/4W	1.38	4W	50/tube	Tube			
TO-263AB	VB30120C-E3/8W	1.38	8W	800/reel	Tape and reel			
TO-262AA	VI30120C-E3/4W	1.46	4W	50/tube	Tube			

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

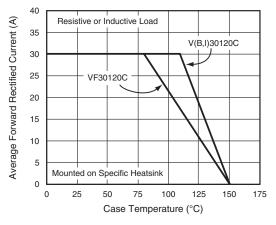


Fig. 1 - Maximum Forward Current Derating Curve

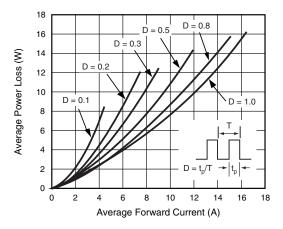
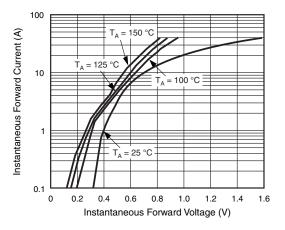


Fig. 2 - Forward Power Loss Characteristics Per Diode

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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

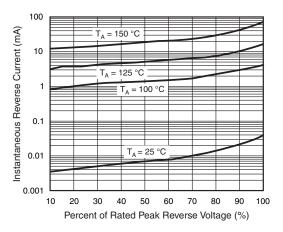


Fig. 4 - Typical Reverse Characteristics Per Diode

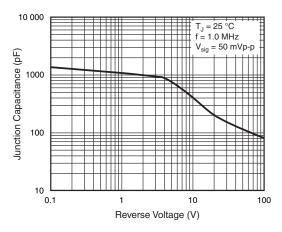


Fig. 5 - Typical Junction Capacitance Per Diode

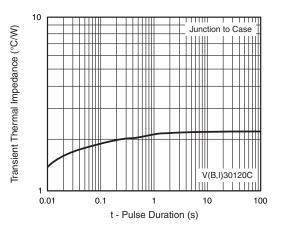


Fig. 6 - Typical Transient Thermal Impedance Per Diode

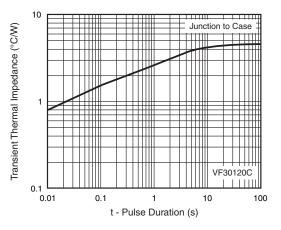


Fig. 7 - Typical Transient Thermal Impedance Per Diode

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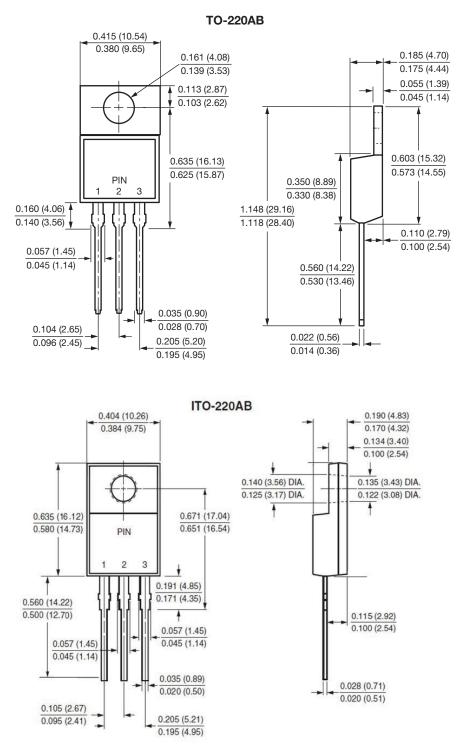
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# **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

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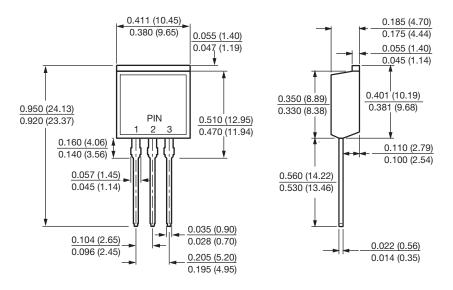
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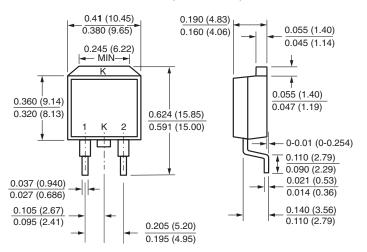
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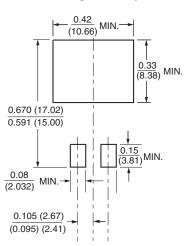
TO-262AA



D<sup>2</sup>PAK (TO-263AB)



**Mounting Pad Layout** 





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